

Silicon Carbide Schottky Barrier Diode

VRRM	1200 V	I _F	10 A
V _{F(Typ.)}	1.5 V	Qc	42 nC

Features

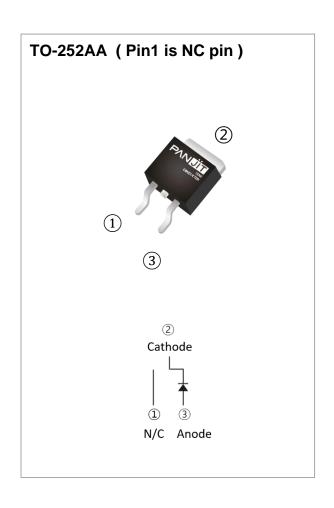
- Temperature Independent Switching Behavior
- High Surge Current Capability
- Positive Temperature Coefficient on V_F
- Low Conduction Loss
- Zero Reverse Recovery
- High junction temperature 175 °C
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: TO-252AA molded plastic
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0113 ounces, 0.3217 grams

Application

• PFC, UPS, PV Inverter, EV Charging Station, Welder



Maximum Ratings and Thermal Characteristics (Tc = 25 °C unless otherwise specified)

PARAMETE	SYMBOL	LIMIT	UNITS		
Repetitive Peak Reverse Voltage		V _{RRM}	1200	V	
DC Blocking Voltage		V _{DC}	1200	V	
Continuous forward current	Tc= 160 °C	l _F	10	А	
Repetitive Peak Surge Current	Tc= 25 °C , t _p =10ms		44	А	
Half Sine Wave, D=0.1	Tc=125 °C , t _p =10ms	FRM	40		
Peak Forward Surge Current	$T_C= 25 ^{\circ}\text{C}$, $t_p = 10 \text{ms}$		72	А	
Half Sine Wave	$T_C=125$ °C , $t_p=10$ ms		64		
Peak Forward Surge Current	IFSM	0.40	А		
t_p =10us, Pulse		640			
Maximum Power Dissipation	P _{total}	200	W		
Operating Junction Temperature Ra	TJ	-55~175	°C		
Storage Temperature Range	T _{STG}	-55~175	°C		



Electrical Characteristics (T_C = 25 °C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
	.,	I _F = 10 A, T _J = 25 °C	-	1.5	1.7	
Forward voltage drop	VF	I _F = 10 A, T _J = 175 °C	-	2.0	-	V
Reverse leakage current	I _R	V _R = 1200 V, T _J = 25 °C	-	6	100	μA
		V _R = 1200 V, T _J = 175 °C	-	0.04	-	mA
Total Capacitive Charge	Qc	I _F = 10 A, V _R = 800V	-	42	1	nC
Total Capacitance	O	V _R = 1V, f = 1MHz	-	529	ı	pF
		V _R = 400V, f = 1MHz	-	36	ı	pF
		V _R = 800V, f = 1MHz	-	25	-	pF
Capacitance Stored Energy	Ec	V _R = 800V	-	12	1	μJ
Thermal Resistance	Rejc		-	0.75	-	°C/W



TYPICAL CHARACTERISTIC CURVES

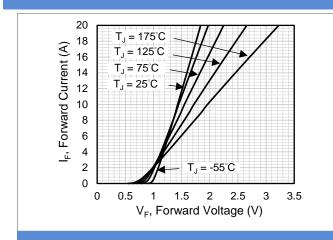


Fig.1 Forward Characteristics

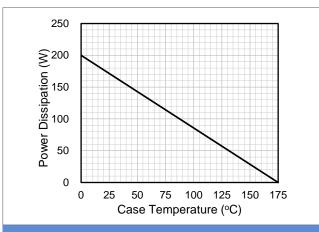


Fig.3 Power Derating Curve

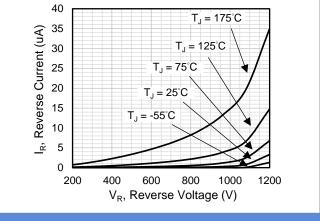


Fig.2 Reverse Characteristics

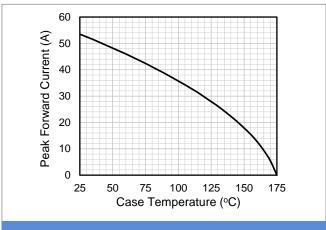
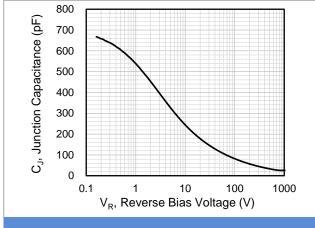


Fig.4 Current Derating Curve





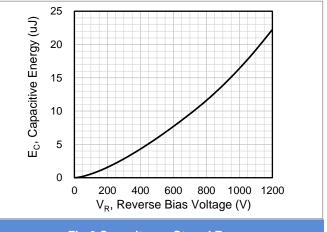


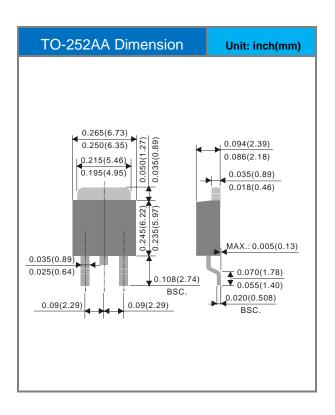
Fig.6 Capacitance Stored Energy

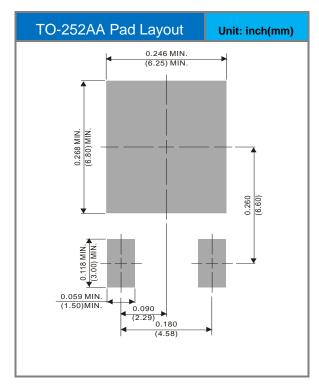


Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PCDC10120G1	TO-252AA	3,000 pcs / 13" reel	CDC10120

Packaging Information & Mounting Pad Layout







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